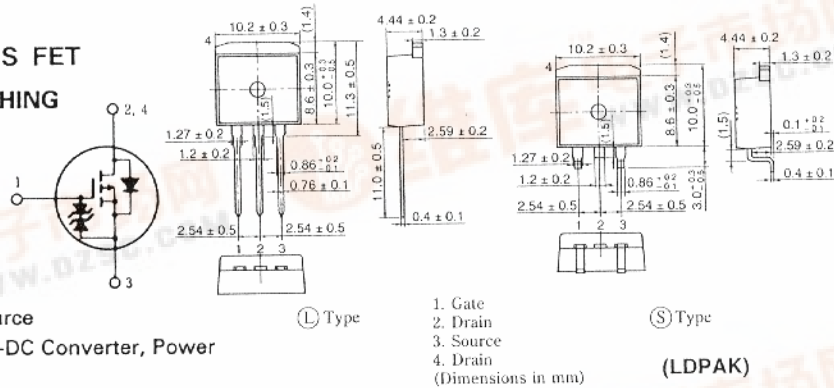


2SJ220(L), 2SJ220(S)

SILICON P-CHANNEL MOS FET
HIGH SPEED POWER SWITCHING

■ FEATURES

- Low On-Resistance
- High Speed Switching
- Low Drive Current
- 4 V Gate Drive Device
 - Can be driven from 5 V source
- Suitable for Motor Drive, DC-DC Converter, Power Switch and Solenoid Drive

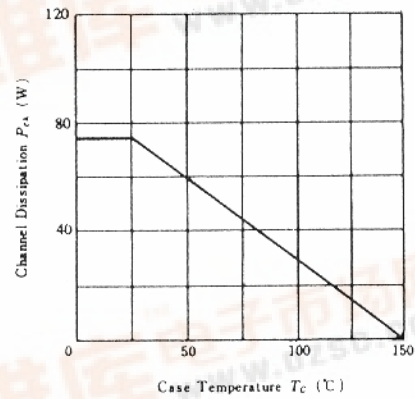


■ ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Item	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current	I_D	-20	A
Drain Peak Current	$I_{D(pk)}$ *	-80	A
Body-Drain Diode Reverse Current	I_{DR}	-20	A
Channel Dissipation	P_{ch} **	75	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	-55 ~ +150	°C

*PW ≤ 10 μs, duty cycle ≤ 1%
**Value at Tc = 25°C

POWER VS. TEMPERATURE DERATING



■ ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DS}$	$I_D = -10mA, V_{GS} = 0$	-60	—	—	V
Gate-Source Breakdown Voltage	$V_{(BR)GS}$	$I_G = ±100μA, V_{DS} = 0$	±20	—	—	V
Gate-Source Leak Current	I_{GSS}	$V_{GS} = ±16V, V_{DS} = 0$	—	—	±10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -50V, V_{GS} = 0$	—	—	-250	μA
Gate-Source Cutoff Voltage	$V_{GS(off)}$	$I_D = -1mA, V_{DS} = -10V$	-1.0	—	-2.0	V
Static Drain-Source-on State Resistance	$R_{DS(on)}$	$I_D = -10A, V_{GS} = -10V^*$	—	0.065	0.085	Ω
		$I_D = -10A, V_{GS} = -4V^*$	—	0.09	0.13	Ω
Forward Transfer Admittance	$ y_{fs} $	$I_D = -10A, V_{DS} = -10V^*$	8	13	—	S
Input Capacitance	C_{iss}	$V_{DS} = -10V, V_{GS} = 0, f = 1MHz$	—	1850	—	pF
Output Capacitance	C_{oss}		—	990	—	pF
Reverse Transfer Capacitance	C_{rss}		—	265	—	pF
Turn-on Delay Time	$t_{d(on)}$		—	15	—	ns
Rise Time	t_r	$I_D = -10A, V_{DS} = -10V, R_L = 3Ω$	—	125	—	ns
Turn-off Delay Time	$t_{d(off)}$		—	345	—	ns
Fall Time	t_f		—	235	—	ns
Body-Drain Diode Forward Voltage	V_{DF}	$I_F = -20A, V_{GS} = 0$	—	-1.2	—	V
Body-Drain Diode Reverse Recovery Time	t_{rr}	$I_F = -20A, V_{GS} = 0, di_T/dt = 50A/μs$	—	230	—	ns

*Pulse Test
■ See characteristic curves of 2SJ174

